

■ General Description

The AME8803/8814 family of positive, linear regulators feature low quiescent current (30 μ A typ.) with low dropout voltage, making them ideal for battery applications. The space-saving SOT-23-6 package is attractive for "Pocket" and "Hand Held" applications.

These rugged devices have both Thermal Shutdown, and Current Fold-back to prevent device failure under the "Worst" of operating conditions.

An additional feature is a "Power Good" detector, which pulls low when the output is out of regulation. In applications requiring a low noise, regulated supply, place a 1000pF capacitor between Bypass and ground.

The AME8803/8814 is stable with an output capacitance of 2.2 μ F or greater.

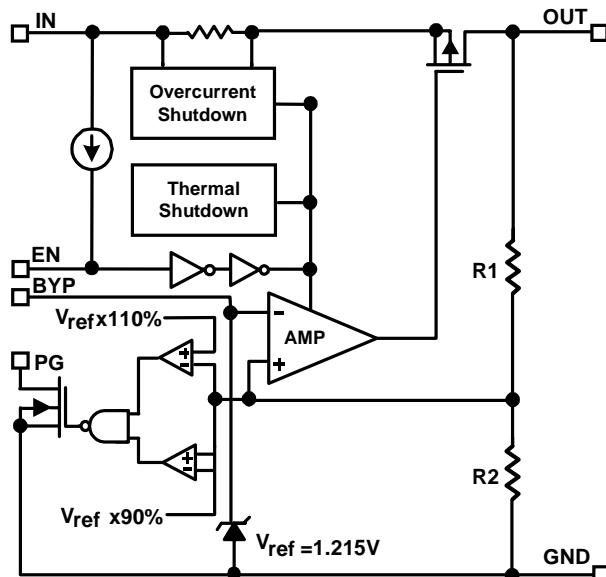
■ Features

- Very Low Dropout Voltage
- Guaranteed 300mA Output
- Accurate to within 1.5%
- 30 μ A Quiescent Current
- Over-Temperature Shutdown
- Current Limiting
- Short Circuit Current Fold-back
- Noise Reduction Bypass Capacitor
- Power Good Detector
- Power-Saving Shutdown Mode
- Space-Saving SOT-26 (SOT-23-6)
- Factory Pre-set Output Voltages
- Low Temperature Coefficient

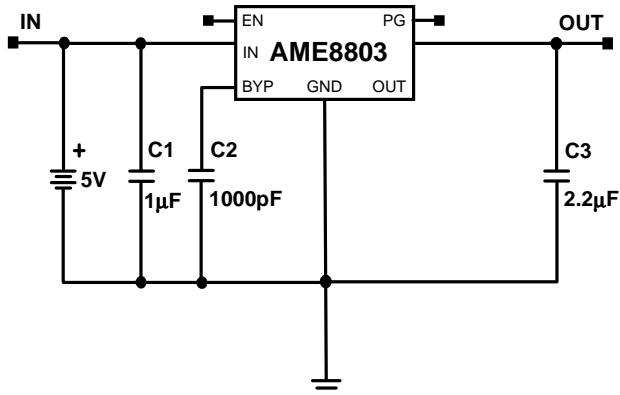
■ Applications

- Instrumentation
- Portable Electronics
- Wireless Devices
- Cordless Phones
- PC Peripherals
- Battery Powered Widgets
- Electronic Scales

■ Functional Block Diagram



■ Typical Application



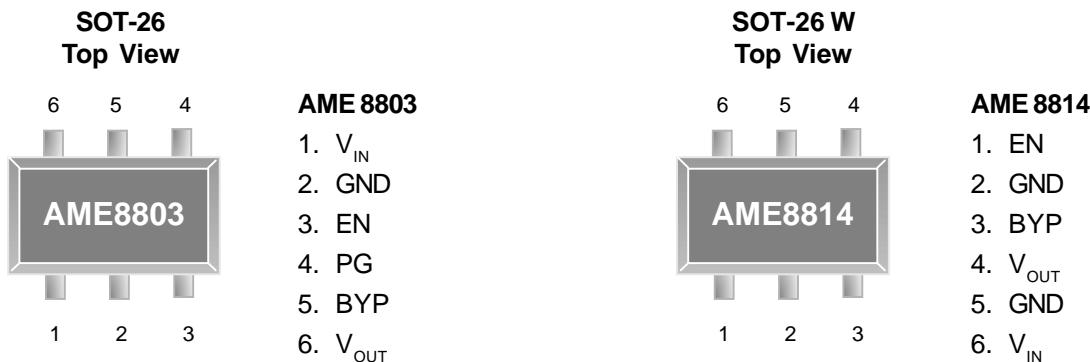


AME, Inc.

AME8803 / 8814

300mA CMOS LDO

■ Pin Configuration



■ Ordering Information

Part Number	Marking	Output Voltage	Package	Operating Temp. Range
AME8803AEEY	AAPww	3.3V	SOT-26	- 40°C to + 85°C
AME8803BEEY	AAQww	3.0V	SOT-26	- 40°C to + 85°C
AME8803CEEY	AARww	2.8V	SOT-26	- 40°C to + 85°C
AME8803DEEY	AASww	2.5V	SOT-26	- 40°C to + 85°C
AME8803EEEY	AATww	3.8V	SOT-26	- 40°C to + 85°C
AME8803FEEY	ABQww	3.6V	SOT-26	- 40°C to + 85°C
AME8803GEEY	ACHww	3.5V	SOT-26	- 40°C to + 85°C
AME8803HEEY	AGKww	2.7V	SOT-26	- 40°C to + 85°C
AME8803IEEY	AEQww	3.4V	SOT-26	- 40°C to + 85°C
AME8803JEEY	AGSww	2.85V	SOT-26	- 40°C to + 85°C
AME8803KEEY	AHUww	3.7V	SOT-26	- 40°C to + 85°C
AME8803LEEY	AJKww	1.5V	SOT-26	- 40°C to + 85°C
AME8803MEEY	AJLww	1.8V	SOT-26	- 40°C to + 85°C
AME8803NEEY	ALAww	2.9V	SOT-26	- 40°C to + 85°C
AME8803OEEY	ALBww	3.1V	SOT-26	- 40°C to + 85°C

**AME8803 / 8814****300mA CMOS LDO****■ Ordering Information (contd.)**

Part Number	Marking	Output Voltage	Package	Operating Temp. Range
AME8814AEEY	AIEww	3.3V	SOT-26	- 40°C to + 85°C
AME8814BEEY	AIFww	3.0V	SOT-26	- 40°C to + 85°C
AME8814CEEY	AIGww	2.8V	SOT-26	- 40°C to + 85°C
AME8814DEEY	AIHww	2.5V	SOT-26	- 40°C to + 85°C
AME8814EEEY	Allww	3.8V	SOT-26	- 40°C to + 85°C
AME8814FEEY	AIJww	3.6V	SOT-26	- 40°C to + 85°C
AME8814GEEY	AIKww	3.5V	SOT-26	- 40°C to + 85°C
AME8814HEEY	AILww	2.7V	SOT-26	- 40°C to + 85°C
AME8814IEEY	AIMww	3.4V	SOT-26	- 40°C to + 85°C
AME8814JEEY	AINww	2.85V	SOT-26	- 40°C to + 85°C
AME8814KEEY	AIOWw	3.7V	SOT-26	- 40°C to + 85°C
AME8814LEEY	AJDww	1.5V	SOT-26	- 40°C to + 85°C
AME8814MEEY	AJEww	1.8V	SOT-26	- 40°C to + 85°C
AME8814NEEY	AKYww	2.9V	SOT-26	- 40°C to + 85°C
AME8814OEEY	AKZww	3.1V	SOT-26	- 40°C to + 85°C

Please consult AME sales office or authorized Rep./Distributor for other output voltage and package type availability.



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■ Absolute Maximum Ratings

Parameter	Maximum	Unit
Input Voltage	8	V
Output Current	$P_D / (V_{IN} - V_O)$	mA
Input, Output Voltage	GND - 0.3 to $V_{IN} + 0.3$	V
ESD Classification	B	

Caution: Stress above the listed absolute maximum rating may cause permanent damage to the device

■ Recommended Operating Conditions

Parameter	Rating	Unit
Ambient Temperature Range	- 40 to + 85	°C
Junction Temperature	- 40 to + 125	°C

■ Thermal Information

Parameter	Maximum	Unit
Thermal Resistance (θ_{ja})	260	°C / W
Thermal Resistance (θ_{ja})	260	
Internal Power Dissipation (P_D) ($\Delta T = 100^\circ\text{C}$)	380	mW
Internal Power Dissipation (P_D) ($\Delta T = 100^\circ\text{C}$)	380	
Maximum Junction Temperature	150	°C
Maximum Lead Temperature (10 Sec)	300	



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■ Electrical Specifications

TA = 25°C unless otherwise noted

Parameter	Symbol	Test Condition		Min	Typ	Max	Units
Input Voltage	V _{IN}			Note 1		7	V
Output Voltage Accuracy	V _O	I _O =1mA		-1.5		1.5	%
Dropout Voltage	V _{DROPOUT}	I _O =300mA V _O =V _{O(NOM)} -2.0%	1.2V <= V _{O(NOM)} <= 2.0V		See chart	1300	mV
			2.0V < V _{O(NOM)} <= 2.8V			400	
			2.8V < V _{O(NOM)}			300	
Output Current	I _O	V _O >1.2V		300			mA
Current Limit	I _{LIM}	V _O >1.2V		300	450		mA
Short Circuit Current	I _{SC}	V _O <0.8V			150	300	mA
Quiescent Current	I _Q	I _O =0mA			30	50	μA
Ground Pin Current	I _{GND}	I _O =1mA to 300mA			35		μA
Line Regulation	REG _{LINE}	I _O =1mA V _{IN} =V _O +1 to V _O +2	1.2V <= V _O <= 1.4V	-0.2		0.2	%
			1.4V < V _O <= 2.0V	-0.15		0.15	
			2.0V < V _O < 4.0V	-0.1	0.02	0.1	
			4.0V <= V _O	-0.4	0.2	0.4	
Load Regulation	REG _{LOAD}	I _O =1mA to 300mA		-1	0.2	1	%
Over Temperature Shutdown	OTS				150		°C
Over Temperature Hysteresis	OTH				30		°C
V _O Temperature Coefficient	TC				30		ppm/°C
Power Supply Rejection	PSRR	I _O =100mA C _O =2.2μF	f=1kHz	50			dB
			f=10kHz	20			
			f=100kHz	15			
Output Voltage Noise	eN	f=10Hz to 100kHz I _O =10mA	C _O =2.2μF		30		μVrms
EN Input Threshold	V _{EH}	V _{IN} =2.7V to 7V		2.0		V _{in}	V
	V _{EL}	V _{IN} =2.7V to 7V		0		0.4	V
EN Input Bias Current	I _{EH}	V _{EN} =V _{IN} , V _{IN} =2.7V to 7V				0.1	μA
	I _{EL}	V _{EN} =0V, V _{IN} =2.7V to 7V				0.5	μA
Shutdown Supply Current	I _{SD}	V _{IN} =5V, V _O =0V, V _{EN} <V _{EL}		0.5	1		μA
Shutdown Output Voltage	V _{O,SD}	I _O =0.4mA, V _{EN} <V _{EL}		0		0.4	V
Output Under Voltage	V _{UV}	2.5V <= V _{O(NOM)} <= 5.0V				85	%V _{O(NOM)}
		1.2V <= V _{O(NOM)} < 2.5V				75	
Output Over Voltage	V _{OV}	2.5V <= V _{O(NOM)} <= 5.0V		115			%V _{O(NOM)}
		1.2V <= V _{O(NOM)} < 2.5V		125			
PG Leakage Current	I _{LC}	V _{PG} =7V				1	μA
PG Voltage Rating	V _{PG}	V _O in regulation				7	V
PG Voltage Low	V _{OL}	I _{SINK} =0.4mA				0.4	V

Note1: V_{IN(MIN)}=V_{OUT}+V_{DROPOUT}

Note2: To prevent the Short Circuit Current protection feature from being prematurely activated, the input voltage must be applied before a current source load is applied.



■ Detailed Description

The AME8803/8814 family of CMOS regulators contain a PMOS pass transistor, voltage reference, error amplifier, over-current protection, thermal shutdown, and Power Good detection circuitry.

The P-channel pass transistor receives data from the error amplifier, over-current shutdown, and thermal protection circuits. During normal operation, the error amplifier compares the output voltage to a precision reference. Over-current and Thermal shutdown circuits become active when the junction temperature exceeds 150°C, or the current exceeds 300mA. During thermal shutdown, the output voltage remains low. Normal operation is restored when the junction temperature drops below 120°C.

The AME8803/8814 switches from voltage mode to current mode when the load exceeds the rated output current. This prevents over-stress. The AME8803 also incorporates current foldback to reduce power dissipation when the output is short circuited. This feature becomes active when the output drops below 0.8volts, and reduces the current flow by 65%. Full current is restored when the voltage exceeds 0.8 volts.

■ External Capacitors

The AME8803/8814 is stable with an output capacitor to ground of 2.2 μ F or greater. Ceramic capacitors have the lowest ESR, and will offer the best AC performance. Conversely, Aluminum Electrolytic capacitors exhibit the highest ESR, resulting in the poorest AC response. Unfortunately, large value ceramic capacitors are comparatively expensive. One option is to parallel a 0.1 μ F ceramic capacitor with a 10 μ F Aluminum Electrolytic. The benefit is low ESR, high capacitance, and low overall cost.

A second capacitor is recommended between the input and ground to stabilize Vin. The input capacitor should be at least 0.1 μ F to have a beneficial effect.

A third capacitor can be connected between the BY-PASS pin and GND. This capacitor can be a low cost Polyester Film variety between the value of 0.001 ~ 0.01 μ F. A larger capacitor improves the AC ripple rejection, but also makes the output come up slowly. This "Soft" turn-on is desirable in some applications to limit turn-on surges.

All capacitors should be placed in close proximity to the pins. A "Quiet" ground termination is desirable. This can be achieved with a "Star" connection.

■ Enable

The Enable pin normally floats high. When actively pulled low, the PMOS pass transistor shuts off, and all internal circuits are powered down. In this state, the quiescent current is less than 1 μ A. This pin behaves much like an electronic switch.

■ Power Good

The AME8803/8814 includes the Power Good feature. When the output is not within $\pm 15\%$ of the specified voltage, it pulls low. This can occur under the following conditions:

- 1) Input Voltage too low.
- 2) During Over-Temperature.
- 3) During Over-Current.
- 4) If output is pulled up.

(Note: PG pin is an open-drain output.)

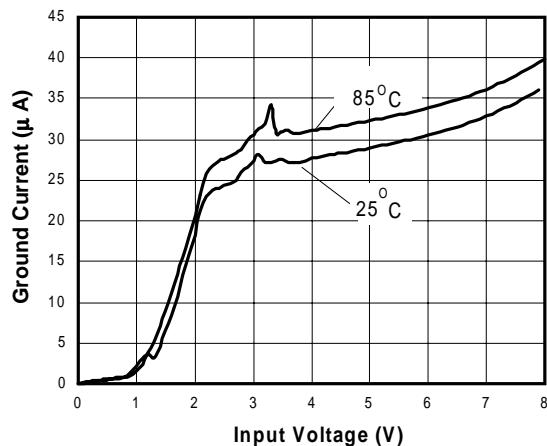


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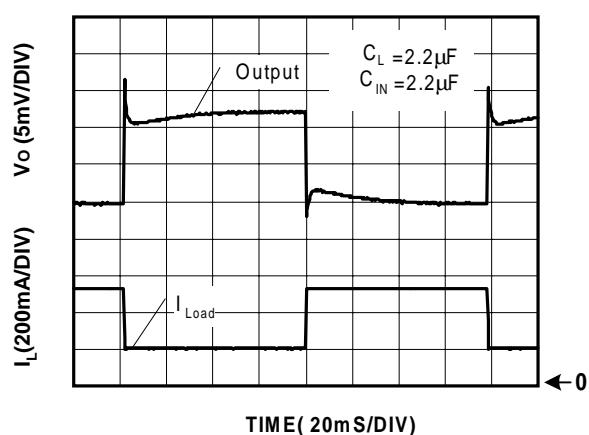
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300mA CMOS LDO

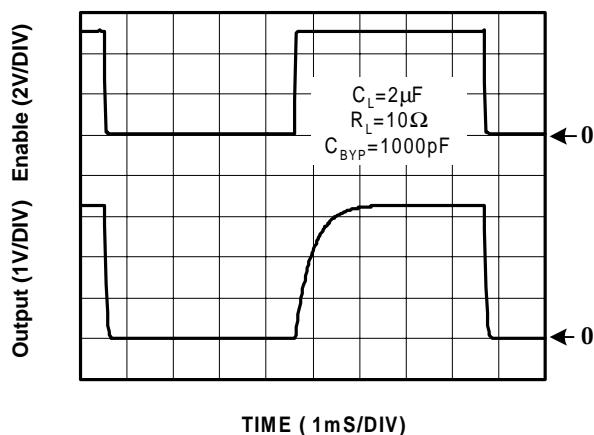
Ground Current vs. Input Voltage



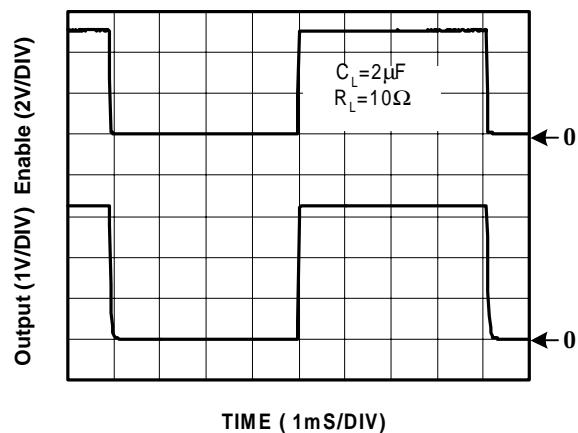
Load Step (1mA-300mA)



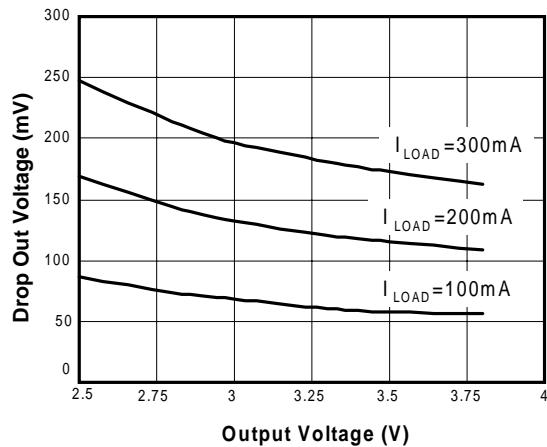
Chip Enable Transient Response



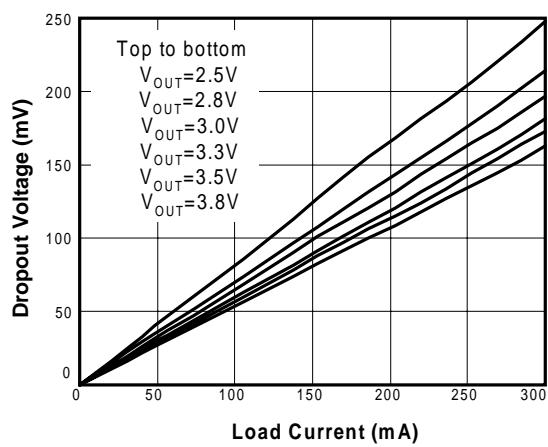
Chip Enable Transient Response



Drop Out Voltage vs. Output Voltage



Drop Out Voltage vs. Load Current



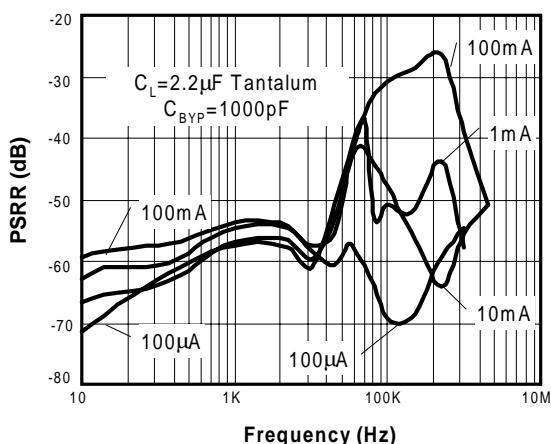


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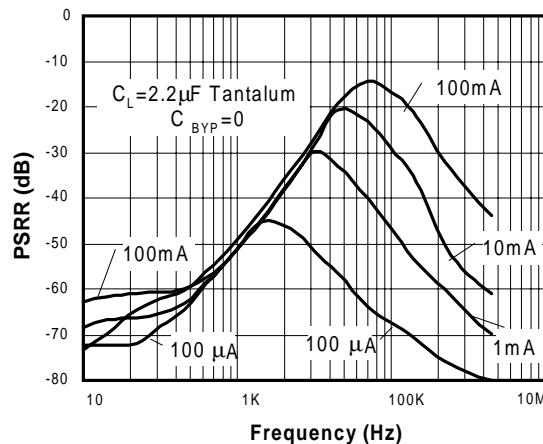
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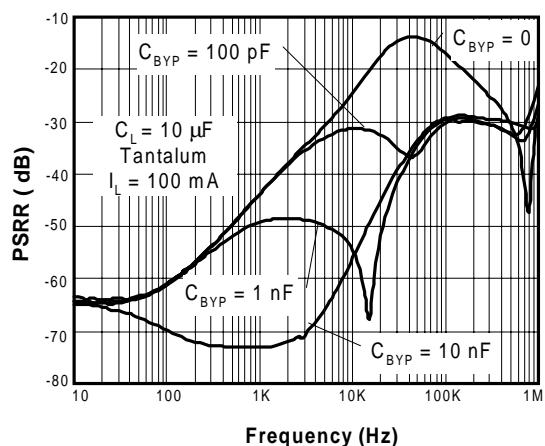
Power Supply Rejection Ratio



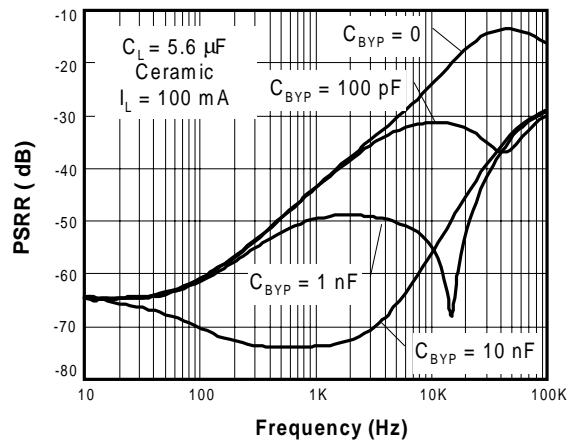
Power Supply Rejection Ratio



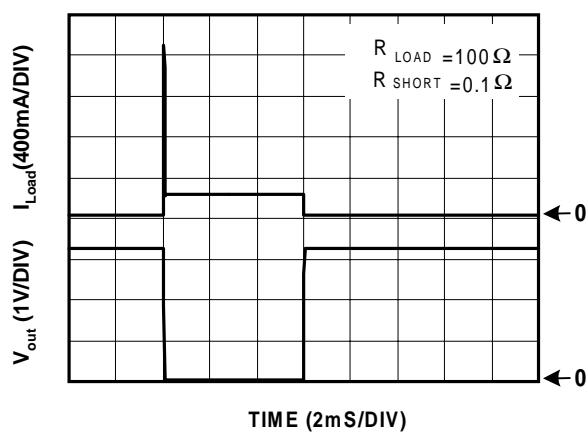
Power Supply Rejection Ratio



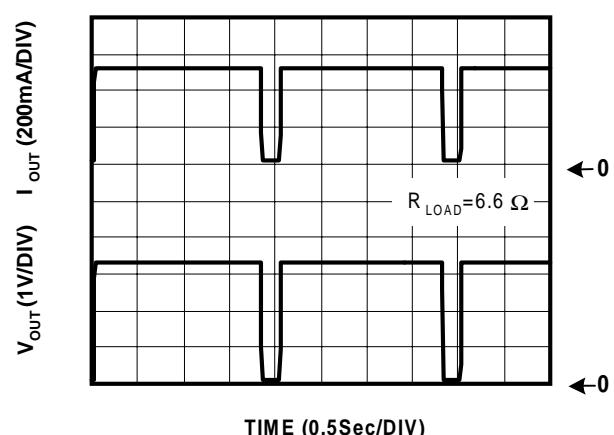
Power Supply Rejection Ratio



Short Circuit Response



Overtemperature Shutdown



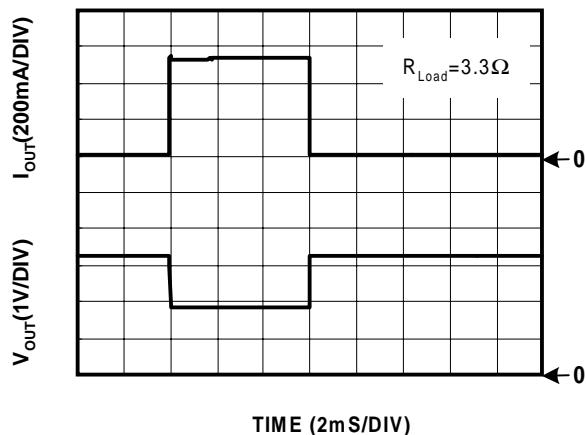


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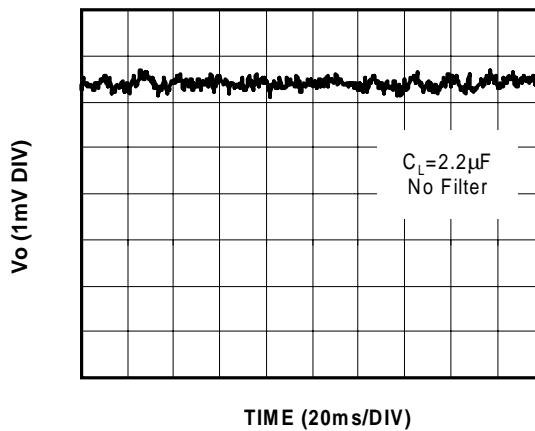
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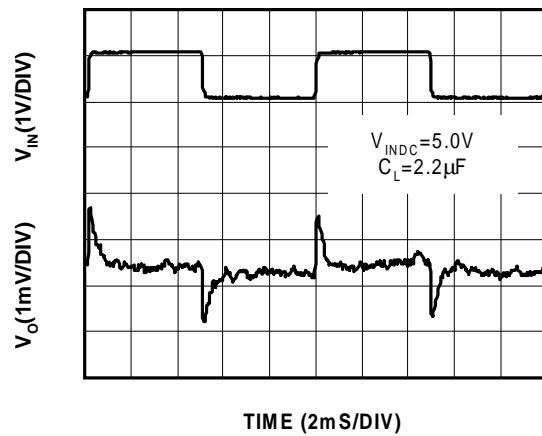
Current Limit Response



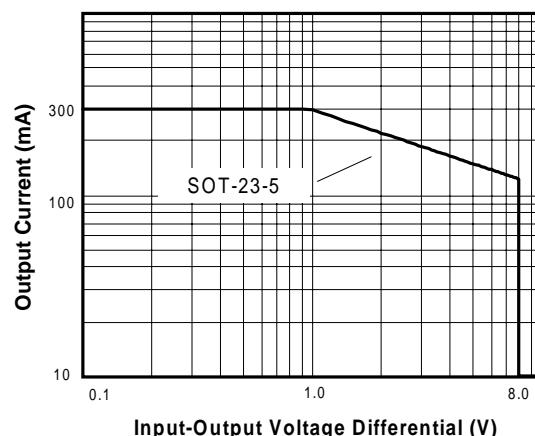
Noise Measurement



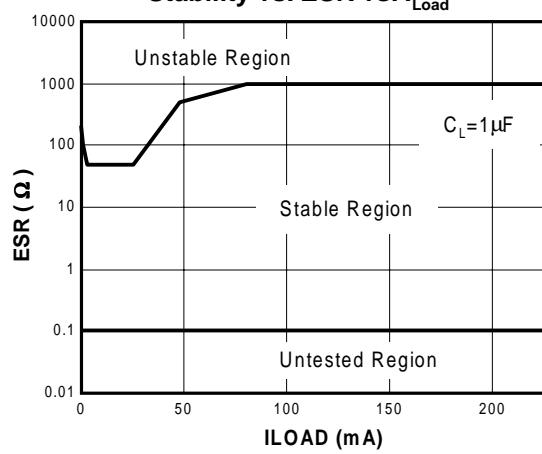
Line Transient Response



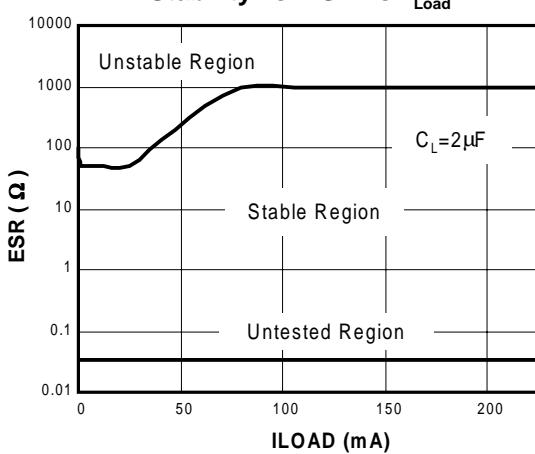
Safe Operating Area



Stability vs. ESR vs. I_{Load}



Stability vs. ESR vs. I_{Load}

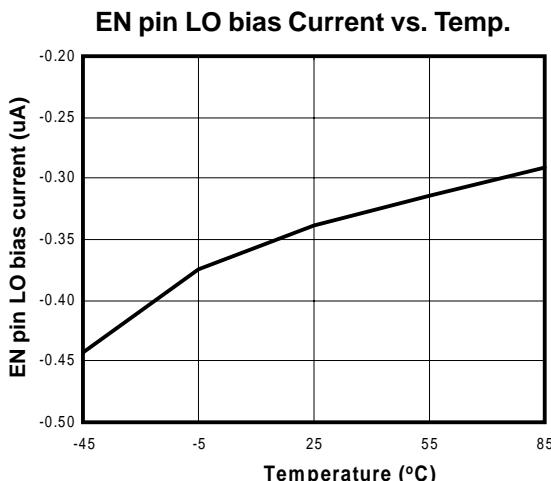
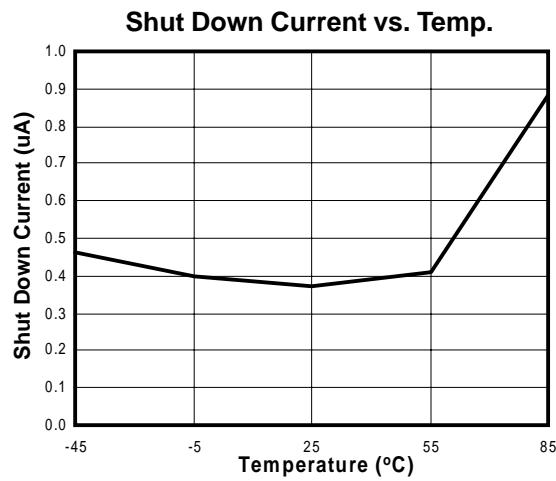
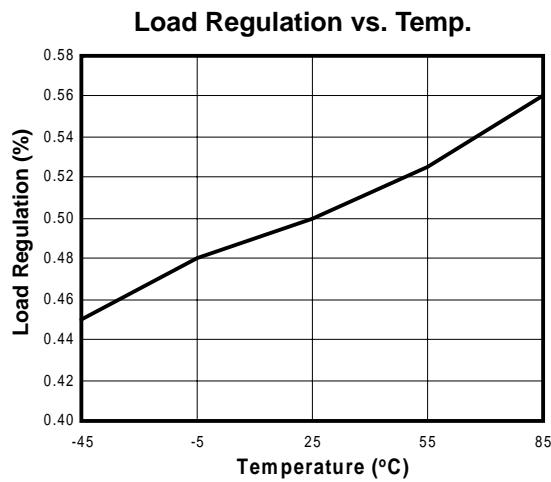
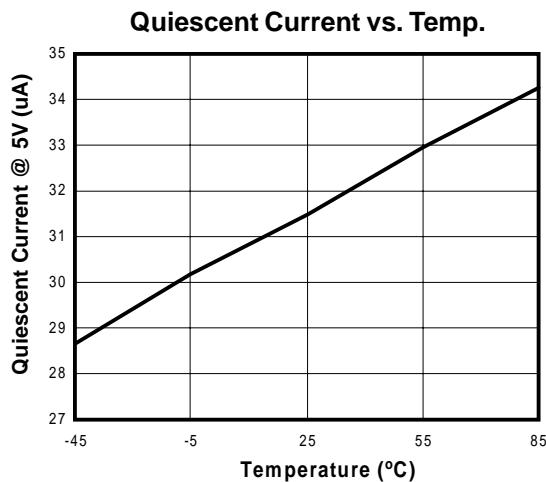
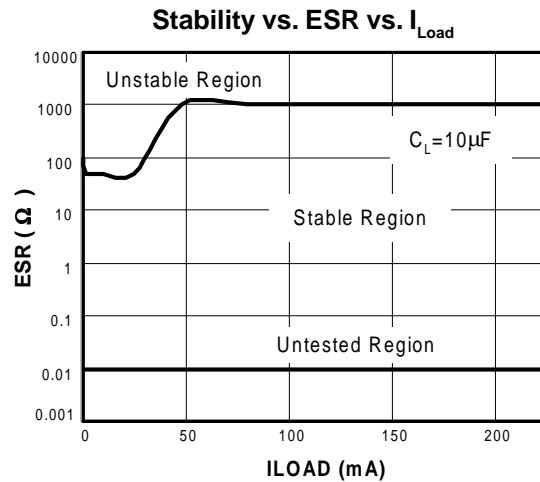
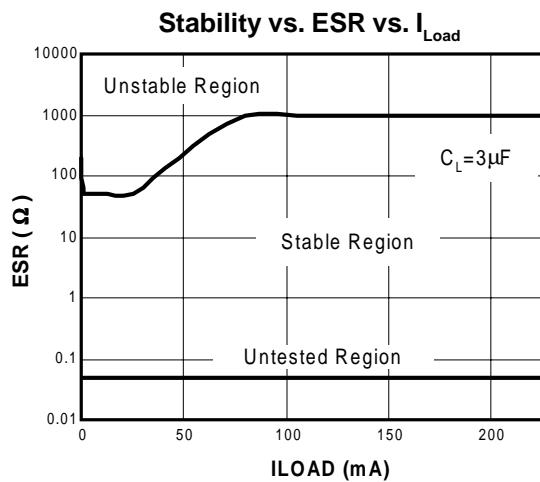




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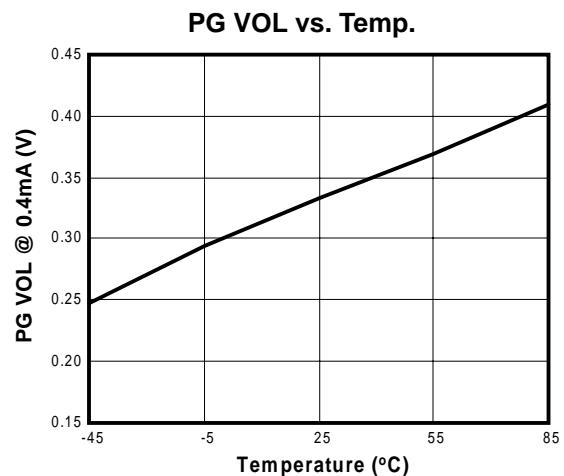
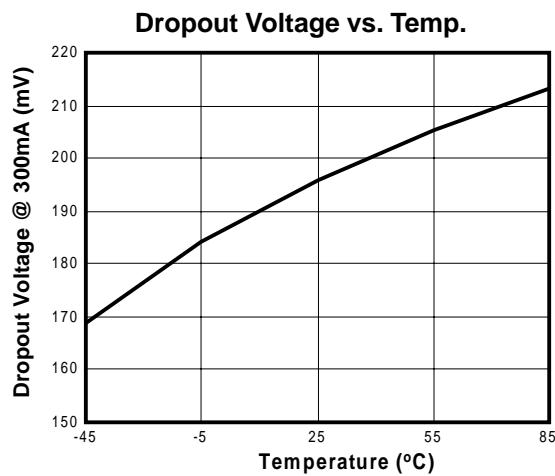




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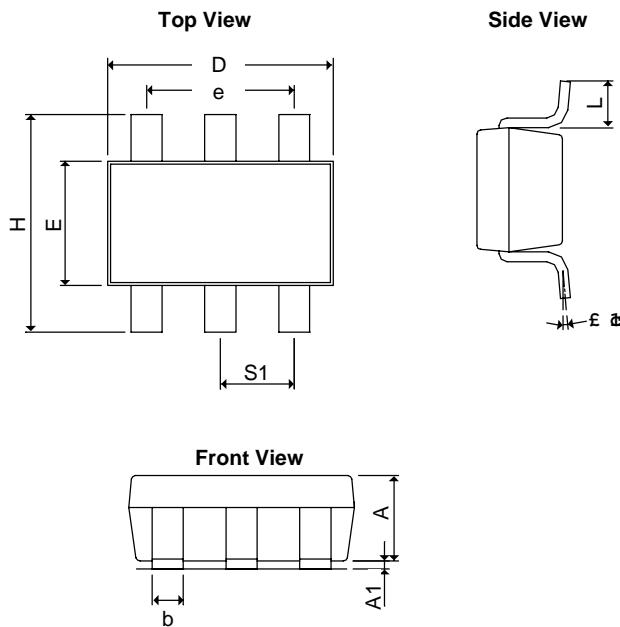
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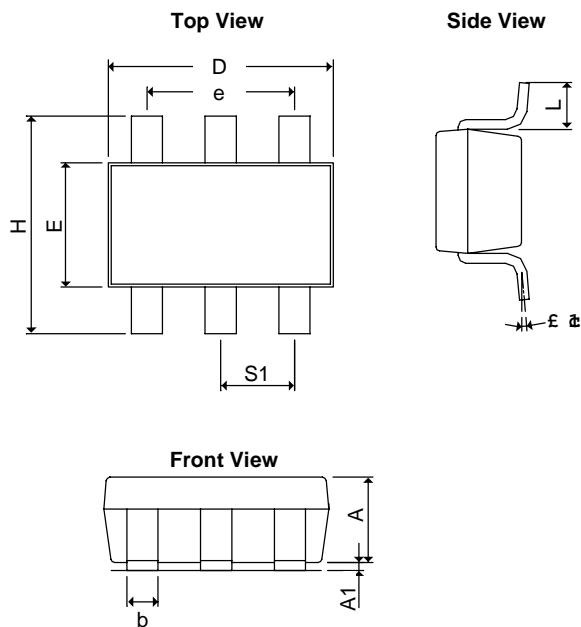
■ Package Dimension

SOT-26(Wide)



SYMBOLS	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.20REF		0.0472REF	
A ₁	0.00	0.15	0.000	0.006
b	0.30	0.55	0.012	0.022
D	2.70	3.10	0.106	0.122
E	1.40	2.00	0.055	0.079
e	1.90REF		0.0748REF	
H	2.60	3.00	0.1024	0.1181
L	0.37REF		0.0146REF	
θ1	0°	10°	0°	10°
S ₁	0.95REF		0.0374REF	

SOT-26



SYMBOLS	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.20REF		0.0472REF	
A ₁	0.00	0.15	0.0000	0.0059
b	0.30	0.55	0.0118	0.0217
D	2.70	3.10	0.1063	0.1220
E	1.40	1.80	0.0551	0.0709
e	1.90 BSC		0.0748 BSC	
H	2.60	3.00	0.10236	0.11811
L	0.37REF		0.0146REF	
θ1	0°	10°	0°	10°
S ₁	0.95REF		0.0374REF	



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AME, Inc. reserves the right to make changes in the circuitry and specifications of its devices and advises its customers to obtain the latest version of relevant information.

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